OMRON MOS FET Relays

G3VM-354J

Analog-switching MOS FET Relay with DPST-NC (Double-pole, Single-throw, Normally Closed) Contacts

- New models with SPST-NC contacts and an 8-pin SOP package now included in 350-V load voltage series.
- Continuous load current of 120 mA.
- Dielectric strength of 1,500 Vrms between I/O.

■ Application Examples

- · Broadband systems
- Measurement devices
- Data loggers
- Amusement machines

■List of Models



Note: The actual product is marked differently from the image shown here.

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
DPST-NC	Surface-mounting	350 VAC	G3VM-354J	50	
	terminals		G3VM-354J(TR)		2,500

Dimensions

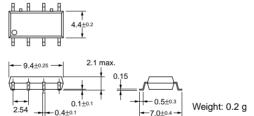
Note: All units are in millimeters unless otherwise indicated.

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from the image shown here.

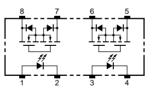
The actual product is marked differently



■ Terminal Arrangement/Internal Connections (Top View)

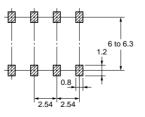
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Note:



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rating Unit		Measurement Conditions	
Input LED forward current Repetitive peak LED forward current		I _F	50	mA		
		I _{FP}	1	A	100 μs pulses, 100 pps	
	LED forward current reduction rate	$\Delta I_{F}^{\circ}C$	-0.5	mA/°C	$Ta \geq 25^\circ C$	
	LED reverse voltage	V _R	5	V		
	Connection temperature	Тј	125	°C		
Output	Output dielectric strength	V _{OFF}	350	V		
	Continuous load current	I _O	120	mA		
	ON current reduction rate	$\Delta I_{ON} / ^{\circ}C$	-1.2	mA/°C	$Ta \geq 25^{\circ}C$	
	Connection temperature	Тј	125	°C		
Dielectric strength between input and output (See note 1.)		V _{I-O}	1,500	Vrms	AC for 1 min	
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation	
Storage temperature		T _{stg}	-55 to +125	°C	With no icing or condensation	
Soldering temperature (10 s)			260	°C	10 s	

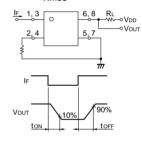
Note:

 The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μA	V _R = 5 V	
	Capacity between terminals	CT		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		1	3	mA	I _{OFF} = 10 μA	
Output	Maximum resistance with output ON	R _{ON}		15	25	Ω	I _O = 120 mA	
	Current leakage when the relay is open	I _{LEAK}			1.0	μA	$V_{OFF} = 350 \text{ V}, I_F = 5 \text{ mA}$	
Capacity between I/O terminals		CI-O		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			MΩ	$\label{eq:VIO} \begin{array}{l} V_{I\text{-}O} = 500 \ \text{VDC}, \\ \text{RoH} \leq 60\% \end{array}$	
Turn-ON time		tON			1.0	ms	$I_{F} = 5 \text{ mA}, R_{L} = 200 \Omega,$ $V_{DD} = 20 \text{ V} \text{ (See note 2.)}$	
Turn-OFF time		tOFF			3.0	ms		





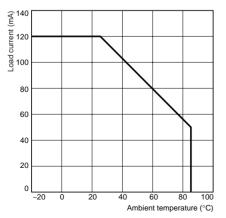
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			280	V
Operating LED forward current	I _F	5		25	mA
Continuous load current	IO			120	mA
Operating temperature	Ta	- 20		65	°C

Engineering Data Load Current vs. Ambient Temperature

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■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.